

Two-Line ESD Protection

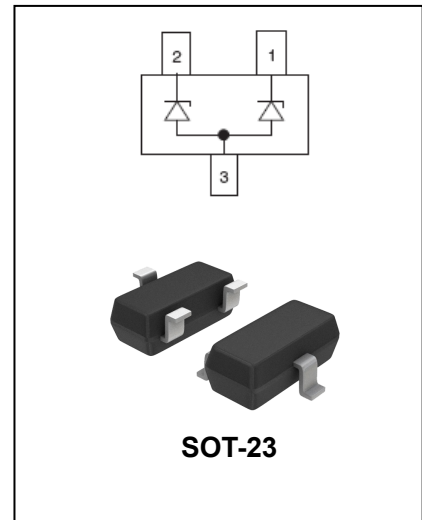
GSOT03C-24C

FEATURES

- Two-line ESD-protection device
- ESD-protection acc. IEC 61000-4-2
 - ± 30 kV contact discharge
 - ± 30 kV air discharge
- AEC-Q101 qualified

APPLICATIONS

- Cell Phone Handsets and Accessories
- Microprocessor based equipment



ORDERING INFORMATION

Type No.	Marking	Package Code
GSOT03C	03C	SOT-23
GSOT05C	05C	SOT-23
GSOT12C	12C	SOT-23
GSOT24C	24C	SOT-23

MAXIMUM RATING @ Ta=25°C unless otherwise specified

GSOT03C				
Parameter	Test Conditions	Symbol	Limits	Unit
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{PP}	369	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		504	
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{PP}	30	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		30	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{PP}	±30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	±30	kV
Operating temperature	Junction temperature	T_j	-55 to+150	°C
Storage temperature	/	T_{STG}	-55 to+150	°C

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GSOT05C				
Parameter	Test Conditions	Symbol	Limits	Unit
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot	P_{PP}	480	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot		612	
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot	I_{PP}	30	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot		30	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{PP}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
Operating temperature	Junction temperature	T_j	-55 to+150	$^{\circ}\text{C}$
Storage temperature	/	T_{STG}	-55 to+150	$^{\circ}\text{C}$

GSOT12C				
Parameter	Test Conditions	Symbol	Limits	Unit
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot	P_{PP}	312	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot		337	
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot	I_{PP}	12	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu\text{s}$; single shot		12	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{PP}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
Operating temperature	Junction temperature	T_j	-55 to+150	$^{\circ}\text{C}$
Storage temperature	/	T_{STG}	-55 to+150	$^{\circ}\text{C}$

**Two-Line ESD Protection****GSOT03C-24C**

GSOT24C				
Parameter	Test Conditions	Symbol	Limits	Unit
Peak pulse power	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	P_{pp}	235	W
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		240	
Peak pulse current	Pin 1 to 3 or pin 2 to 3 acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot	I_{pp}	5	A
	Pin 1 to 2 or pin 2 to 1; pin 3 not connected acc. IEC 61000-4-5, $t_p = 8/20 \mu s$; single shot		5	
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{PP}	± 30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV
Operating temperature	Junction temperature	T_j	-55 to+150	$^{\circ}C$
Storage temperature	/	T_{STG}	-55 to+150	$^{\circ}C$

ELECTRICAL CHARACTERISTICS @ $T_a=25$ unless otherwise specified

GSOT03C						
between pin 1 to pin 3 or pin 2 to pin 3						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	$N_{channel}$			2	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			3.3	V	$I_R=100\mu A$
Reverse current	I_R			100	μA	$V_R=3.3V$
Reverse breakdown voltage	V_{BR}	4	4.6		V	$I_R=1mA$
Clamping voltage	V_C		5.7 10	7.5 12.3	V	$I_{PP}=1A$ $I_{PP}=I_{PPM}=30A$
Forward clamping voltage	V_F		1 4.5	1.2	μA	$I_{PP}=1A$ $I_{PP}=I_{PPM}=30A$
Junction Capacitance	C_D		420 260	600	pF	$V_R=0V, f=1MHz$ $V_R=1.6V, f=1MHz$

Two-Line ESD Protection
GSOT03C-24C

GSOT05C						
between pin 1 to pin 3 or pin 2 to pin 3						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	N_{channel}			2	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			5	V	$I_{\text{R}}=100\mu\text{A}$
Reverse current	I_{R}			10	μA	$V_{\text{R}}=5\text{V}$
Reverse breakdown voltage	V_{BR}	6	6.8		V	$I_{\text{R}}=1\text{mA}$
Clamping voltage	V_{C}		7 12	8.7 16	V	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=30\text{A}$
Forward clamping voltage	V_{F}		1 4.5	1.2	μA	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=30\text{A}$
Junction Capacitance	C_{D}		260 150	350	pF	$V_{\text{R}}=0\text{V},f=1\text{MHz}$ $V_{\text{R}}=2.5\text{V},f=1\text{MHz}$

GSOT12C						
between pin 1 to pin 3 or pin 2 to pin 3						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	N_{channel}			2	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			12	V	$I_{\text{R}}=1\mu\text{A}$
Reverse current	I_{R}			1	μA	$V_{\text{R}}=12\text{V}$
Reverse breakdown voltage	V_{BR}	13.5	15		V	$I_{\text{R}}=1\text{mA}$
Clamping voltage	V_{C}		15.4 21.2	18.7 26	V	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=12\text{A}$
Forward clamping voltage	V_{F}		1 2.2	1.2	μA	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=12\text{A}$
Junction Capacitance	C_{D}		115 50	150	pF	$V_{\text{R}}=0\text{V},f=1\text{MHz}$ $V_{\text{R}}=6\text{V},f=1\text{MHz}$

Two-Line ESD Protection

GSOT03C-24C

GSOT24C between pin 1 to pin 3 or pin 2 to pin 3						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	N_{channel}			2	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			24	V	$I_{\text{R}}=1\mu\text{A}$
Reverse current	I_{R}			1	μA	$V_{\text{R}}=24\text{V}$
Reverse breakdown voltage	V_{BR}	27	30		V	$I_{\text{R}}=1\text{mA}$
Clamping voltage	V_{C}		34 41	41 47	V	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=5\text{A}$
Forward clamping voltage	V_{F}		1 1.4	1.2	μA	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=5\text{A}$
Junction Capacitance	C_{D}		65 20	80	pF	$V_{\text{R}}=0\text{V},f=1\text{MHz}$ $V_{\text{R}}=12\text{V},f=1\text{MHz}$

GSOT03C between pin 1 to pin 2 or pin 2 to pin1; pin 3 not connected						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	N_{channel}			1	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			3.8	V	$I_{\text{R}}=100\mu\text{A}$
Reverse current	I_{R}			100	μA	$V_{\text{R}}=3.8\text{V}$
Reverse breakdown voltage	V_{BR}	4.5	5.3		V	$I_{\text{R}}=1\text{mA}$
Clamping voltage	V_{C}		7 14	8.4 16.8	V	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=30\text{A}$
Junction Capacitance	C_{D}		210 190	300	pF	$V_{\text{R}}=0\text{V},f=1\text{MHz}$ $V_{\text{R}}=1.6\text{V},f=1\text{MHz}$

Two-Line ESD Protection
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GSOT05C						
between pin 1 to pin 2 or pin 2 to pin1; pin 3 not connected						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	N_{channel}			1	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			5.5	V	$I_{\text{R}}=10\mu\text{A}$
Reverse current	I_{R}			10	μA	$V_{\text{R}}=5.5\text{V}$
Reverse breakdown voltage	V_{BR}	6.5	7.5		V	$I_{\text{R}}=1\text{mA}$
Clamping voltage	V_{C}		8.1 17	9.7 20.4	V	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=18\text{A}$
Junction Capacitance	C_{D}		130 100	175	pF	$V_{\text{R}}=0\text{V},f=1\text{MHz}$ $V_{\text{R}}=4\text{V},f=1\text{MHz}$

GSOT12C						
between pin 1 to pin 2 or pin 2 to pin1; pin 3 not connected						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	N_{channel}			1	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			12.5	V	$I_{\text{R}}=1\mu\text{A}$
Reverse current	I_{R}			1	μA	$V_{\text{R}}=12.5\text{V}$
Reverse breakdown voltage	V_{BR}	13.5	15.7		V	$I_{\text{R}}=1\text{mA}$
Clamping voltage	V_{C}		16.4 23.4	19.7 28.1	V	$I_{\text{PP}}=1\text{A}$ $I_{\text{PP}}= I_{\text{PPM}}=12\text{A}$
Junction Capacitance	C_{D}		58 36	75	pF	$V_{\text{R}}=0\text{V},f=1\text{MHz}$ $V_{\text{R}}=7.5\text{V},f=1\text{MHz}$

Two-Line ESD Protection

GSOT03C-24C

GSOT24C						
between pin 1 to pin 2 or pin 2 to pin1; pin 3 not connected						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Protection paths	$N_{channel}$			1	lines	Number of lines which can be protected
Reverse stand-off voltage	V_{RWM}			24.5	V	$I_R=1\mu A$
Reverse current	I_R			1	μA	$V_R=24.5V$
Reverse breakdown voltage	V_{BR}	27.5	30.7		V	$I_R=1mA$
Clamping voltage	V_C		34 40	41 48	V	$I_{PP}=1A$ $I_{PP}=I_{PPM}=5A$
Junction Capacitance	C_D		33 18	40	pF	$V_R=0V, f=1MHz$ $V_R=12V, f=1MHz$

TYPICAL CHARACTERISTICS @ $T_a=25^\circ C$ unless otherwise specified

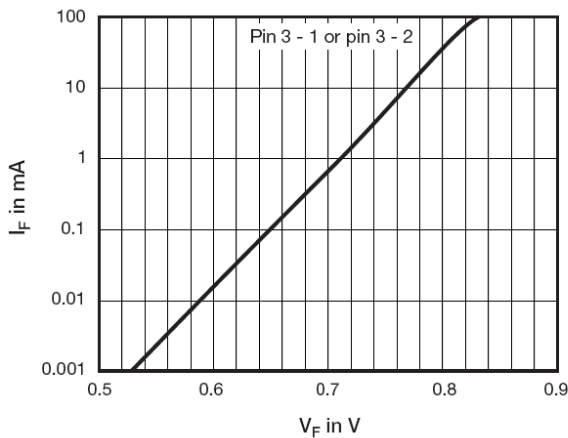


Fig. 1 - Typical Forward Current I_F vs. Forward Voltage V_F

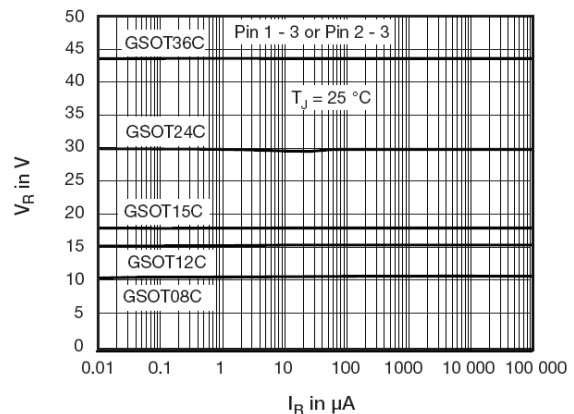


Fig. 2 - Typical Reverse Voltage V_R vs. Reverse Current I_R

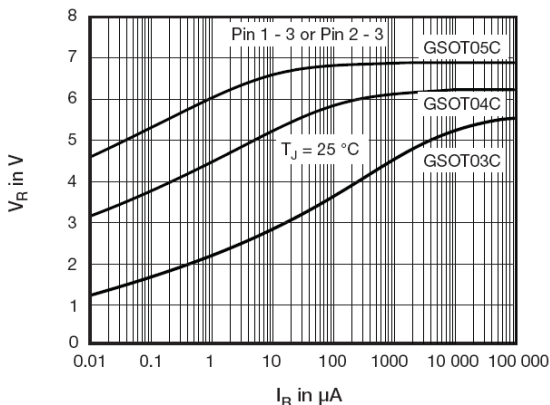


Fig. 3 - Typical Reverse Voltage V_R vs. Reverse Current I_R

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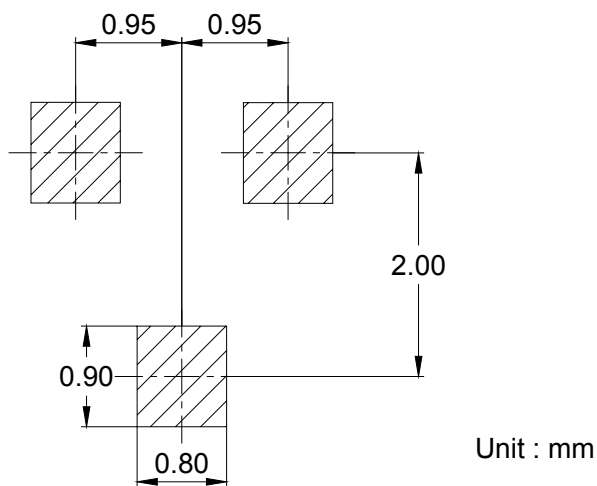
PACKAGE OUTLINE

Plastic surface mounted package

SOT-23

SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60
All Dimensions in mm		

SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
GSOT03C-24C	SOT-23	3000/Tape&Reel